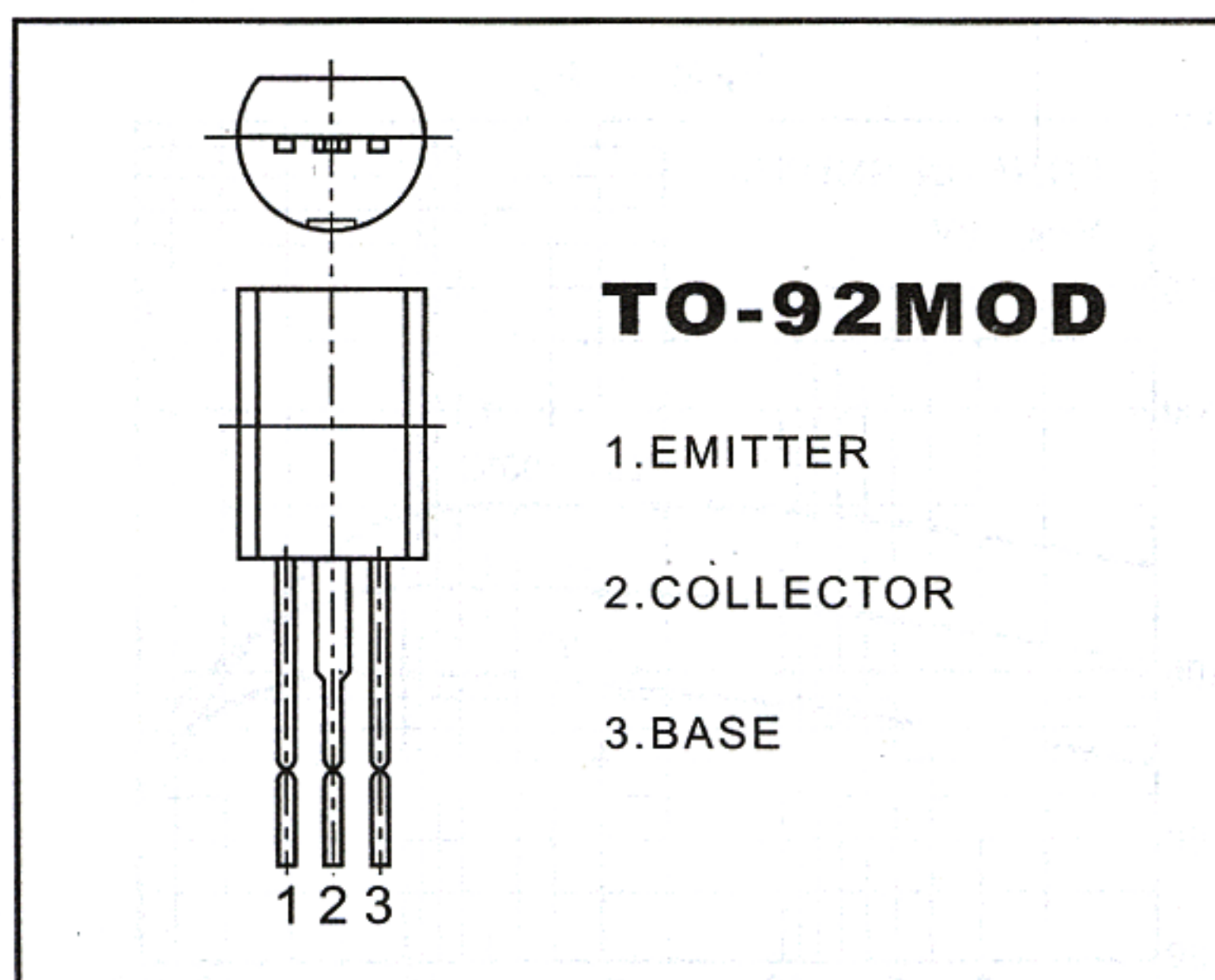


2SC1627A TRANSISTOR(NPN)



FEATURES

Power dissipation

P_{CM} : 0.8W ($T_{amb}=25^{\circ}C$)

Collector current

I_{CM} : 0.4 A

Collector-base voltage

$V_{(BR)CBO}$: 80 V

Operating and storage junction temperature range

T_J, T_{stg} : $-55^{\circ}C$ to $+150^{\circ}C$

ELECTRICAL CHARACTERISTICS

($T_{amb}=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 100 \mu A, I_E = 0$	80		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 5 mA, I_B = 0$	80		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = 100 \mu A, I_C = 0$	5		V
Collector cut-off current	I_{CBO}	$V_{CB} = 50 V, I_E = 0$		0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 5 V, I_C = 0$		0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE} = 2 V, I_C = 50 mA$	70	240	
	$h_{FE(2)}$	$V_{CE} = 2 V, I_C = 200 mA$	40		
Collector-emitter saturation voltage	V_{CEsat}	$I_C = 200 mA, I_B = 20 mA$		0.4	V
Base-emitter voltage	V_{BE}	$V_{CE} = 2 V, I_C = 50 mA$	0.55	0.8	V
Transition frequency	f_T	$V_{CE} = 10 V, I_C = 10 mA$	80		MHz

CLASSIFICATION OF $h_{FE(1)}$

Rank	O	Y
Range	70-140	120-240

Typical Characteristics

2SC1627A

